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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR Phase-out/Discontinued NP84N03KUF

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP84N03KUF is N-channel MOS Field Effect Transistor designed for high current applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE
NP84N03KUF	TO-263 (MP-25ZK)

FEATURES

- Channel temperature 175 degree rating
- Super low on-state resistance
 R_{DS(on)} = 3.0 mΩ MAX. (V_{GS} = 10 V, I_D = 42 A)
- Low Ciss: Ciss = 5000 pF TYP.

(TO-263)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

	Drain to Source Voltage (V _{GS} = 0 V)	VDSS	30	V
	Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
	Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±84	Α
	Drain Current (pulse) Note1	D(pulse)	±336	Α
	Total Power Dissipation (T _A = 25°C)	P _{T1}	1.8	W
*	Total Power Dissipation (Tc = 25°C)	P _{T2}	200	W
	Channel Temperature	Tch	175	°C
	Storage Temperature	Tstg	-55 to +175	°C
	Single Avalanche Current Note2	las	72	Α
	Single Avalanche Energy Note2	Eas	518	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 15 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

THERMAL RESISTANCE

*	★ Channel to Case Thermal Resistance	Rth(ch-C)	0.75	°C/W
	Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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90%



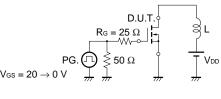


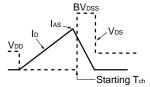
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V			1.0	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage Note	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 42 A	29	57		S
Drain to Source On-state Resistance Note	RDS(on)	V _{GS} = 10 V, I _D = 42 A		2.4	3.0	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		5000	7500	pF
Output Capacitance	Coss	V _{GS} = 0 V		1200	1800	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		380	685	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 42 A		29	64	ns
Rise Time	tr	V _{GS} = 10 V		18	45	ns
Turn-off Delay Time	td(off)	R _G = 0 Ω		85	170	ns
Fall Time	tf			15	38	ns
Total Gate Charge	Q _G	V _{DD} = 24 V		90	135	nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		20		nC
Gate to Drain Charge	Q _{GD}	I _D = 84 A		25		nC
Body Diode Forward Voltage Note	V _F (S-D)	I _F = 84 A, V _{GS} = 0 V		0.93	1.5	V
Reverse Recovery Time	trr	I _F = 84 A, V _{GS} = 0 V		70		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		110		nC

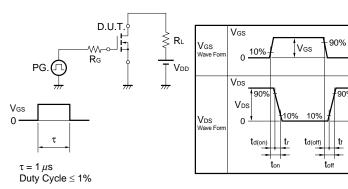
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

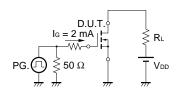




TEST CIRCUIT 2 SWITCHING TIME



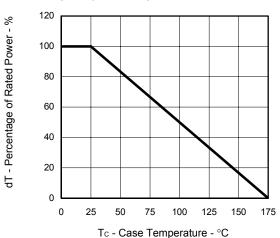
TEST CIRCUIT 3 GATE CHARGE



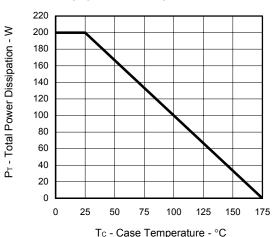


TYPICAL CHARACTERISTICS (TA = 25°C)

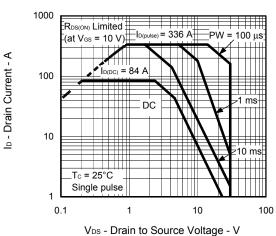
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



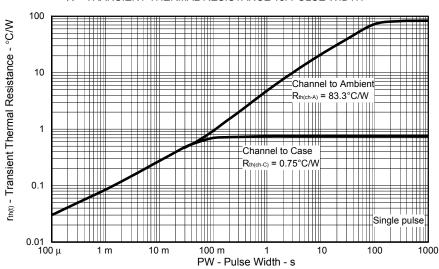
★ TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



★ FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

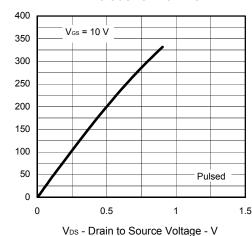


Ip - Drain Current - A

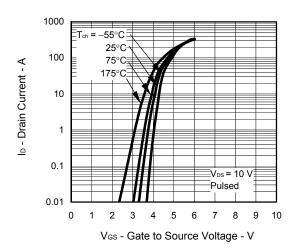
Ves(th) - Gate to Source Threshold Voltage - V



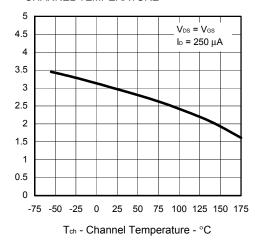
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



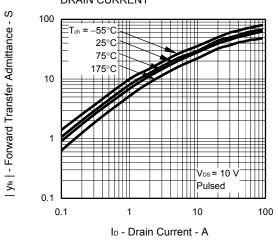
FORWARD TRANSFER CHARACTERISTICS



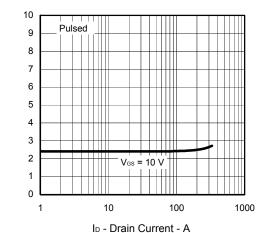
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



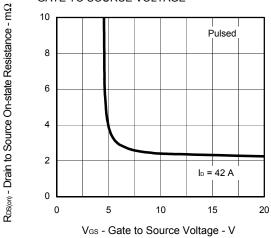
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

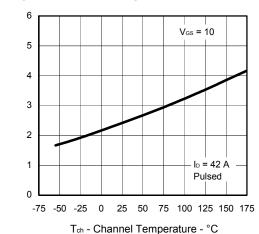


R_{DS(m)} - Drain to Source On-state Resistance - mΩ

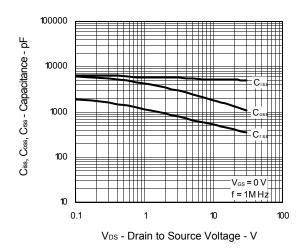
RDS(on) - Drain to Source On-state Resistance - m\Omega



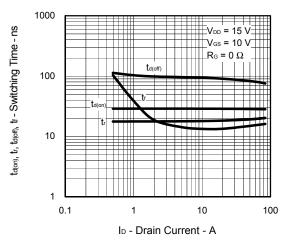
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



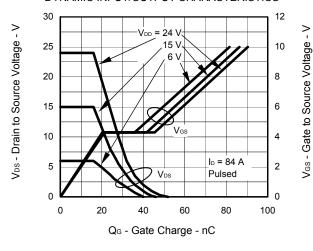
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



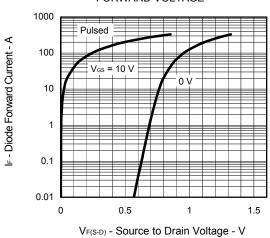
SWITCHING CHARACTERISTICS



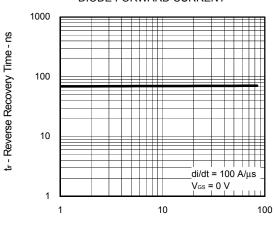
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

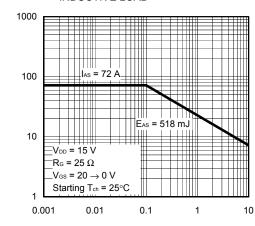


IF - Diode Forward Current - A

IAS - Single Avalanche Current - A

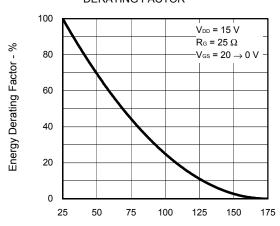


SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



L - Inductive Load - mH

SINGLE AVALANCHE ENERGY DERATING FACTOR

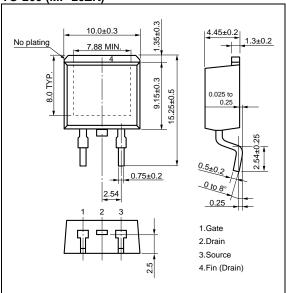


Starting Tch - Starting Channel Temperature - °C

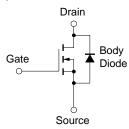


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.



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